Optimization of Graphene Photothermoelectric Detectors

Aron W. Cummings

Aleandro Antidormi
Catalan Institute of Nanoscience and Nanotechnology (ICN2),
CSIC and The Barcelona Institute of Science and Technology,
Campus UAB, Bellaterra, 08193 Barcelona, Spain
aron.cummings@icn2.cat

Owing to its unique properties, graphene is a promising material for a wide range of applications [1]. Particularly promising are applications that utilize several of graphene's unique properties in a single system or device. A perfect example of such devices are photodetectors based on the photothermoelectric effect (PTE) in graphene, which combine a broadband and fast photoresponse with high signal-to-noise ratio and minimal power consumption [2-5]. There are many design parameters impacting the performance of these devices, including the light profile, the device geometry, and the material quality.

In this talk, I will discuss the impact that these design parameters have on the performance of PTE-based graphene photodetectors, and I will demonstrate how their performance may be optimized. Careful tuning of the light profile and device geometry can improve the photoresponse by more than one order of magnitude. Detector performance can also be improved with higher graphene material quality, but only to a point. When material quality is too high, Peltier cooling can degrade the photoresponse, indicating an upper bound on device performance and suggesting that ultraclean graphene may be unnecessary for, and actually detrimental to, the performance of these detectors [6].

References

- [1] AC Ferrari et al., Nanoscale **7**, 4598 (2015)
- [2] X Cai et al., Nat Nanotechnol 9, 814 (2014)
- [3] S Schuler et al., Nano Lett 16, 7107 (2016)
- [4] S Castilla et al., Nano Lett 19, 2765 (2019)
- [5] J Muench et al., Nano Lett 19, 7632 (2019)
- [6] A Antidormi and AW Cummings, Phys Rev Appl 15, 054049 (2021)



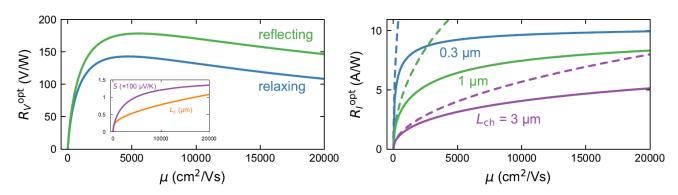


Figure 1: Optimal photovoltage (left) and photocurrent (right) as a function of graphene carrier mobility. In both cases, the photoresponse saturates for a mobility around 5000 cm²/Vs.